NSN 5961-01-163-9014

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View Online at https://aerobasegroup.com/nsn/5961-01-163-9014 **Inclosure Material:** Metal **Overall Length:** 1.253 inches **Function For Which Designed:** Rectifier **Mounting Facility Quantity: Electrode Internally-electrically Connected To Case:** Anode **Mounting Method:** Threaded stud **Terminal Circle Diameter:** 0.250 inches **Features Provided:** Hermetically sealed case and mounting hardware and reverse polarity **Overall Width Across Flats:** 0.437 inches Thready Qty Per Inch (tpi): 32 **Thread Size:** 0.190 inches **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 200.0 working peak reverse voltage **Current Rating Per Characteristic:** 12.0 amperes average forward current averaged over a full 60-hz cycle **Maximum Operating Tempurature Per Measurement Point:** 200.0 degrees celsius case **Product Name:** Clamping diode assembly **Special Features:** This is a assembly consisting of connecting link diode mounting bracket pn 29813-001, rectifier diode type jan 1n1202ra pn 29814-001, wire red tfe 2.500 lg 16 awg pn 20021-306, ring tongue terminal pn 10476-009, shrink tubbing0.750 lg pn 25517-001, hex nut 10/32 pn 15111-058, belleville washer pn 16128-028 **Thread Series Designator:** Unf **Terminal Type And Quantity:** 1 tab w/wire lead and 1 threaded stud

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N/a

Shelf Life:

Unit Of Measure:

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Demilitarization:

Yes - demil/mli

Fiig:

A110a0